

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

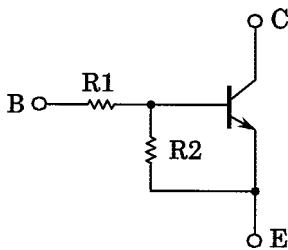
# RN1507, RN1508, RN1509

Switching, Inverter Circuit, Interface Circuit  
And Driver Circuit Applications

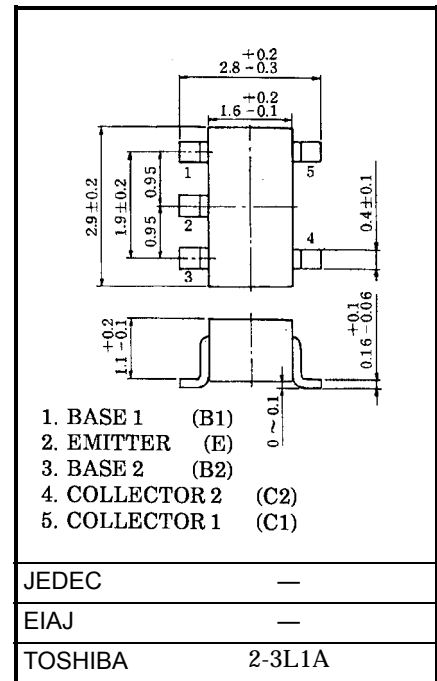
Unit in mm

- Including two devices in SMV (super mini type with 5 leads) With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2507~RN2509

## Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN1907	10	47
RN1908	22	47
RN1909	47	22



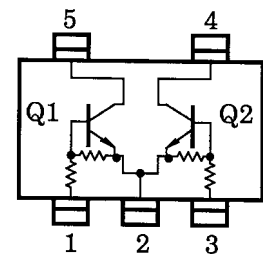
Weight: 0.014g

## Equivalent Circuit (Top View)

## Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic	Symbol	Rating	Unit	
Collector-base voltage	RN1507~1509	$V_{CBO}$	50	V
Collector-emitter voltage		$V_{CEO}$	50	V
Emitter-base voltage	$V_{EBO}$	RN1507	6	V
		RN1508	7	
		RN1509	15	
Collector current	RN1507~1509	$I_C$	100	mA
Collector power dissipation		$P_C^*$	300	mW
Junction temperature		$T_j$	150	°C
Storage temperature range		$T_{stg}$	-55~150	°C

\* : Total rating

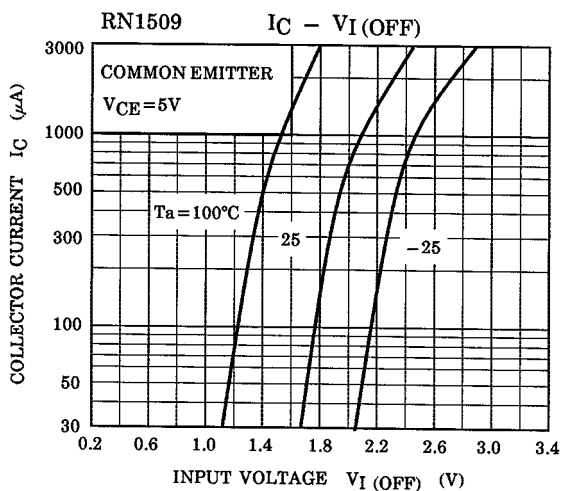
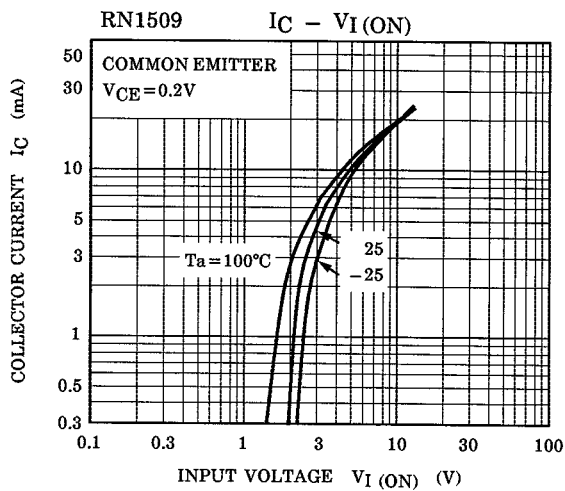
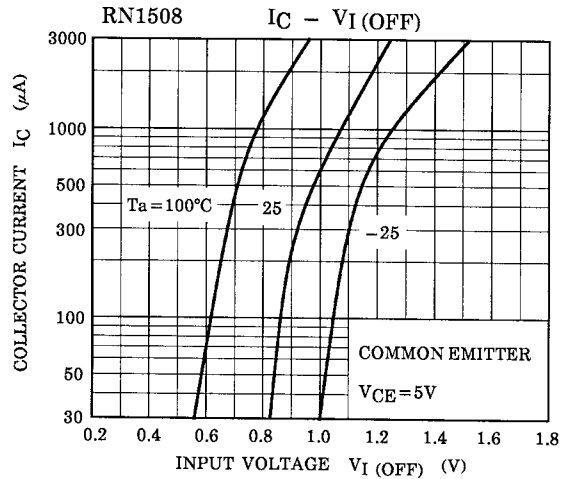
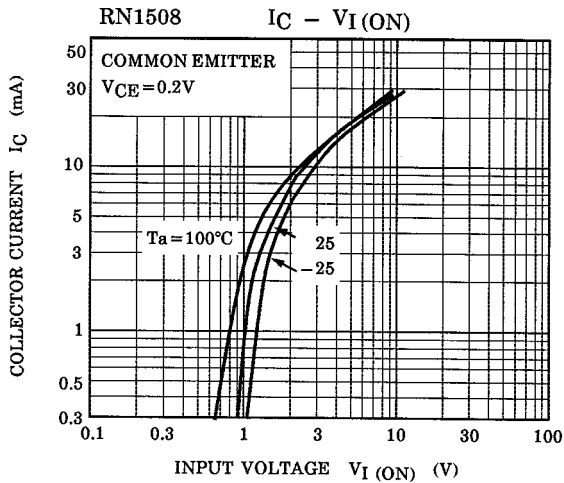
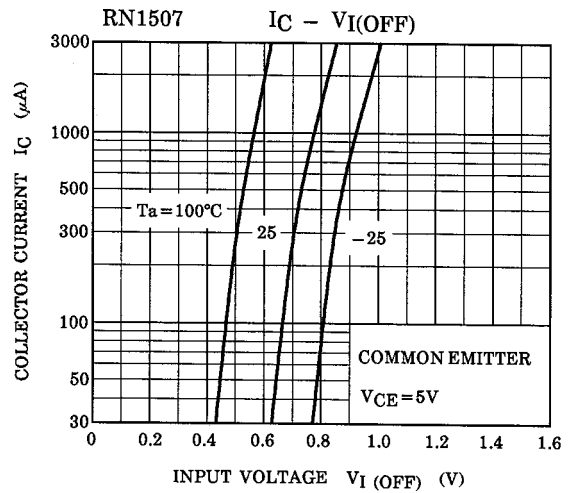
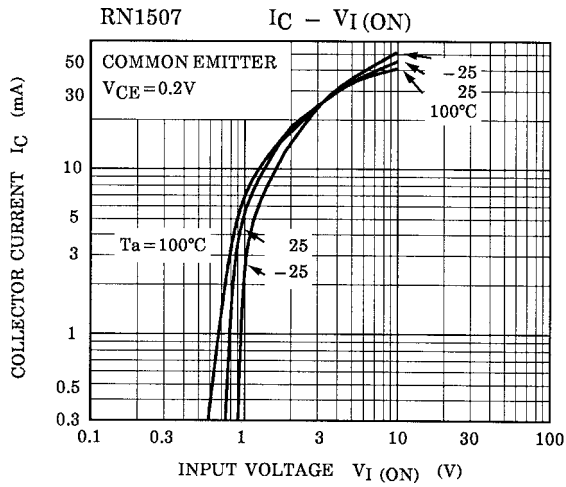


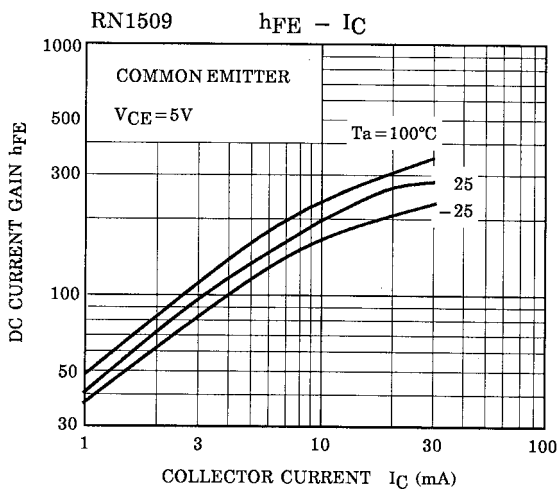
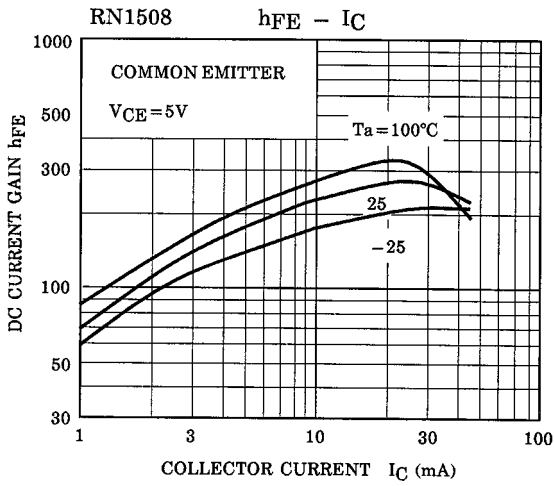
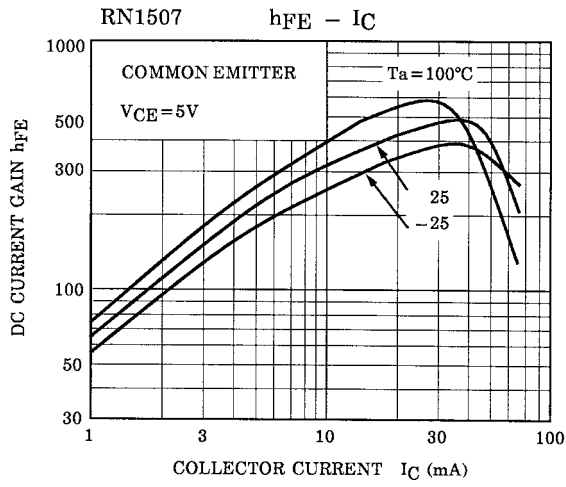
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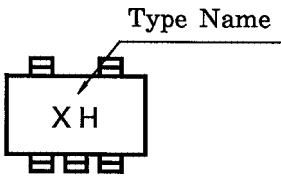
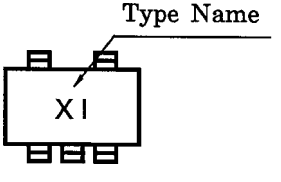
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**Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)**

Characteristic		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN1507~1509	$I_{CBO}$	—	$V_{CB} = 50V, I_E = 0$	—	—	100	nA
		$I_{CEO}$		$V_{CE} = 50V, I_B = 0$	—	—	500	nA
Emitter cut-off current	RN1507	$I_{EBO}$	—	$V_{EB} = 6V, I_C = 0$	0.081	—	0.15	mA
	RN1508			$V_{EB} = 7V, I_C = 0$	0.078	—	0.145	
	RN1509			$V_{EB} = 15V, I_C = 0$	0.167	—	0.311	
DC current gain	RN1507	$h_{FE}$	—	$V_{CE} = 5V, I_C = 10mA$	80	—	—	
	RN1508				80	—	—	
	RN1509				70	—	—	
Collector-emitter saturation voltage	RN1507~1509	$V_{CE(sat)}$	—	$I_C = 5mA, I_B = 0.25mA$	—	0.1	0.3	V
Input voltage (ON)	RN1507	$V_{I(ON)}$	—	$V_{CE} = 0.2V, I_C = 5mA$	0.7	—	1.8	V
	RN1508				1.0	—	2.6	
	RN1509				2.2	—	5.8	
Input voltage (OFF)	RN1507	$V_{I(OFF)}$	—	$V_{CE} = 5V, I_C = 0.1mA$	0.5	—	1.0	V
	RN1508				0.6	—	1.16	
	RN1509				1.5	—	2.6	
Transition frequency	RN1507~1509	$f_T$	—	$V_{CE} = 10V, I_C = 5mA$	—	250	—	MHz
Collector Output capacitance	RN1507~1509	$C_{ob}$	—	$V_{CB} = 10V, I_E = 0, f = 1MHz$	—	3	6	pF
Input resistor	RN1507	R1	—		7	10	13	kΩ
	RN1508				15.4	22	28.6	
	RN1509				32.9	47	61.1	
Resistor ratio	RN1507	R1/R2	—		0.191	0.213	0.232	
	RN1508				0.421	0.468	0.515	
	RN1509				1.92	2.14	2.35	





Type Name	Marking
RN1507	
RN1508	
RN1509	